

## Descriptions

This-30V -4.2A P-Channel MOSFET in a SOT-23-6 Plastic Package.

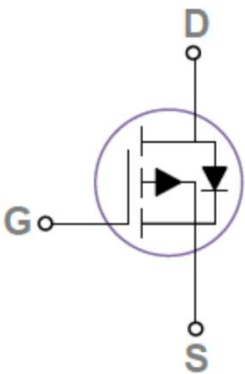
## Features

- $V_{DS}(V)=-30V$
- $I_D=-4.2A(V_{GS}=-10V)$
- $R_{DS}(ON)<50m\Omega(V_{GS}=-10V)$
- $R_{DS}(ON)<65m\Omega(V_{GS}=-4.5V)$

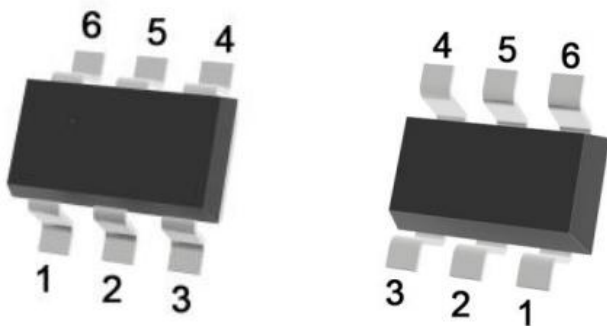
## Applications

This device is suitable for use as a load switch or in PWM applications.

## Equivalent Circuit



## Pinning



PIN1, PIN 2, PIN 5, PIN 6 : Drain

PIN 3: Gate

PIN 4: Source

### Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DSS}$	-30	V
Drain Current – Continuous	$I_D(T_a=25^\circ\text{C})$	-4.2	A
Drain Current- Continuous <sup>A</sup>	$I_D(T_a=70^\circ\text{C})$	-3.5	A
Pulsed Drain Current <sup>B</sup>	$I_{DM}$	-30	A
Gate-Source Voltage	$V_{GS}$	±12	V
Maximum Power Dissipation <sup>A</sup>	$P_D(T_a=25^\circ\text{C})$	1.4	W
Total Power Dissipation <sup>A</sup>	$P_D(T_a=70^\circ\text{C})$	1.0	W
Maximum Junction-to-Ambient <sup>(Note 1)</sup>	$R_{\theta JA}$	125	°C/W
Maximum Junction-to-Lead <sup>C</sup>	$R_{\theta JL}$	60	°C/W
Junction and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ 150	°C

### Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V \quad I_D=-250\mu A$	-30			V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=-24V \quad V_{GS}=0V$ $T_j=25^\circ\text{C}$			-1	μA
		$V_{DS}=-24V \quad V_{GS}=0V$ $T_j=55^\circ\text{C}$			-5	μA
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V \quad V_{DS}=0V$			±0.1	uA
On-State Drain Current	$I_{D(on)}$	$V_{GS}=-4.5V \quad V_{DS}=-5V$	-25			A
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS} \quad I_D=-250\mu A$	-1.0		-2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V \quad I_D=-4.2A$		37	50	mΩ
	$R_{DS(on)}$	$V_{GS}=-10V \quad I_D=-4.2A$ $T_j=125^\circ\text{C}$			75	
	$R_{DS(on)}$	$V_{GS}=-4.5V \quad I_D=-4A$		58	65	
Forward Transconductance	$g_{FS}$	$V_{DS}=-5V \quad I_D=-5A$	7	11		S
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V \quad I_S=-1A$		-0.75	-1.0	V

Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-15V V <sub>GS</sub> =0V f=1MHz		957		pF
Output Capacitance	C <sub>oss</sub>			115		
Reverse Transfer Capacitance	C <sub>rss</sub>			77		
Gate resistance	R <sub>g</sub>	V <sub>GS</sub> =0V V <sub>DS</sub> =0V, f=1MHz		6		Ω
Total Gate Charge	Q <sub>g</sub>	V <sub>GS</sub> =-4.5V V <sub>DS</sub> =-15V I <sub>D</sub> =-4A		9.4		nC
Gate Source Charge	Q <sub>gs</sub>			2		
Gate Drain Charge	Q <sub>gd</sub>			3		
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>GS</sub> =-10V R <sub>L</sub> =3.6Ω V <sub>DS</sub> =-15V R <sub>GEN</sub> =6Ω		6.3		ns
Turn-On Rise Time	t <sub>r</sub>			3.2		
Turn-Off Delay Time	t <sub>d(off)</sub>			38.2		
Turn-Off Fall Time	t <sub>f</sub>			12		
Body Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =-4A, dI/dt=100A/μs		20.2		ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =-4A, dI/dt=100A/μs		11.2		nC

A: The value of R<sub>θJA</sub> is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub>=25°C. The value in any given application depends on the user's specific board design. The current rating is based on the t ≤ 10s thermal resistance rating.

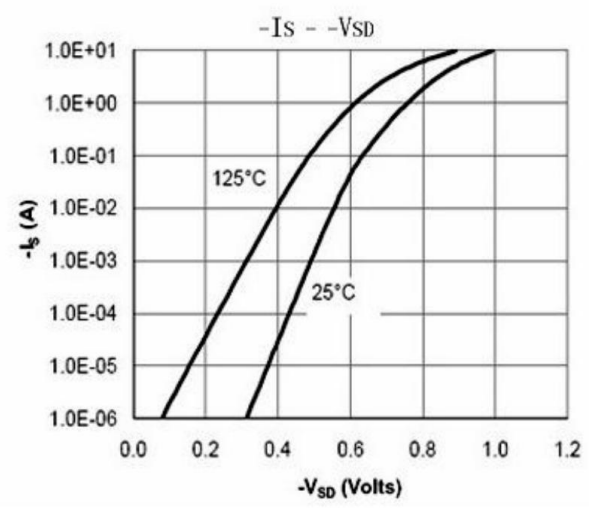
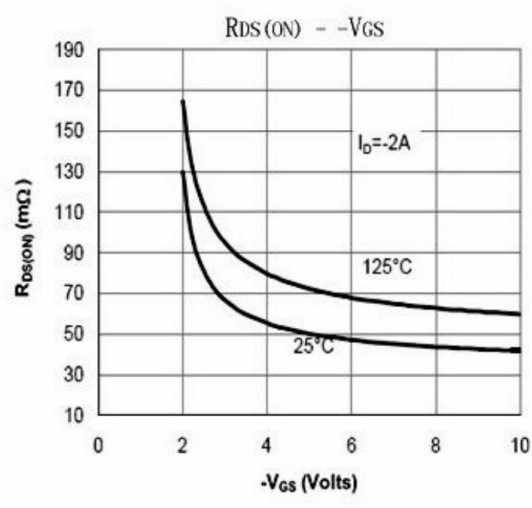
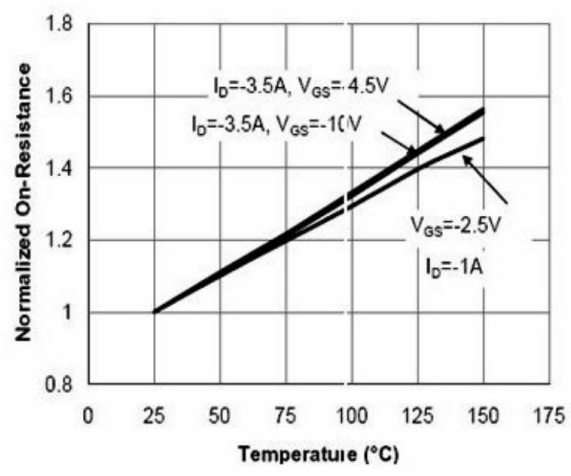
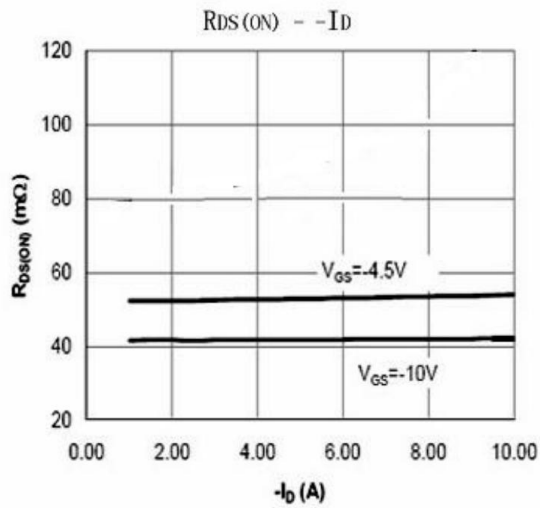
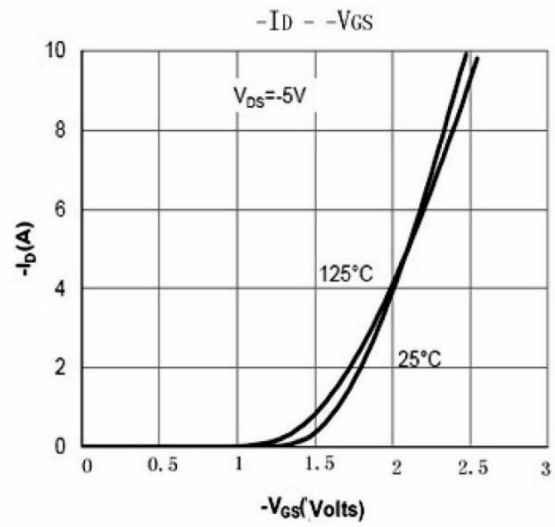
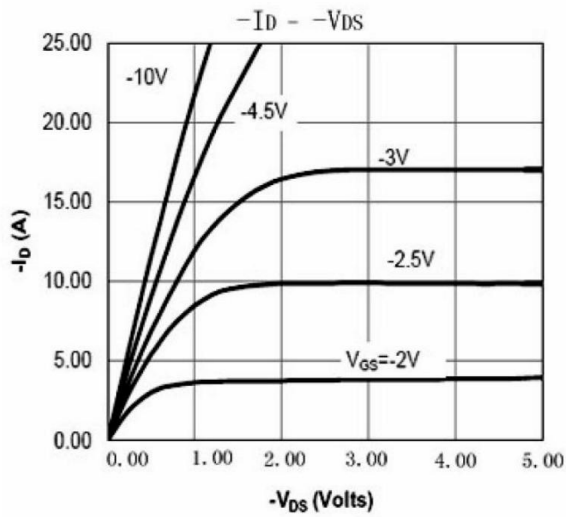
B: Repetitive rating, pulse width limited by junction temperature.

C. The R<sub>θJA</sub> is the sum of the thermal impedance from junction to lead R<sub>θJL</sub> and lead to ambient.

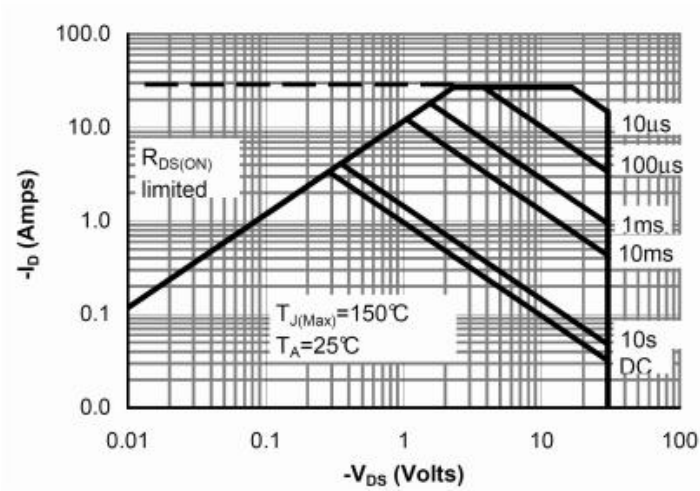
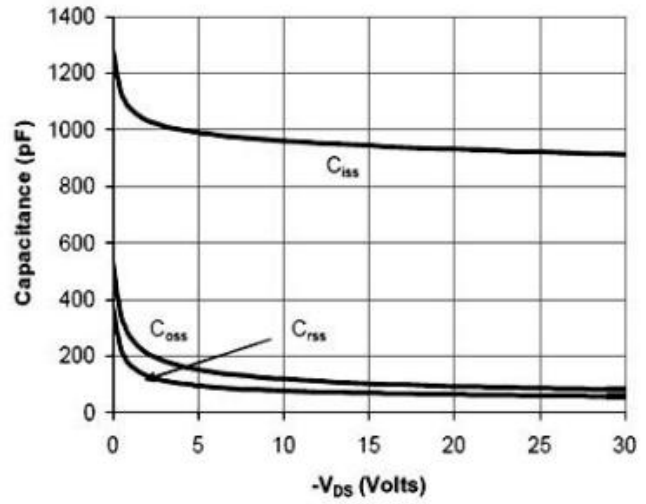
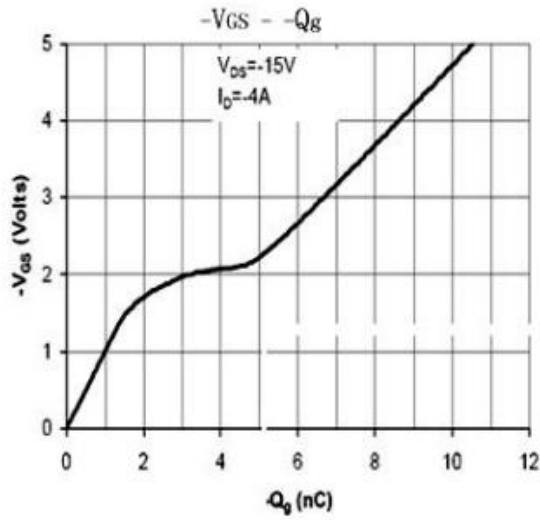
D. The static characteristics in Figures 1 to 6,12,14 are obtained using 80 μs pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub>=25°C. The SOA curve provides a single pulse rating.

Electrical Characteristic Curve



Electrical Characteristic Curve



**Marking Instructions**



Note:

3411: Product Type.

\*\*\*\*: Lot No. Code, code change with Lot No.

**Packaging SPEC**

REEL INFORMATION

Package Type	Units					Dimension (unit: mm <sup>3</sup> )		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
SOT23-6	3,000	10	30,000	4	120,000	7" ×8	210×205×205	445×230×435

Package Outline Dimensions

